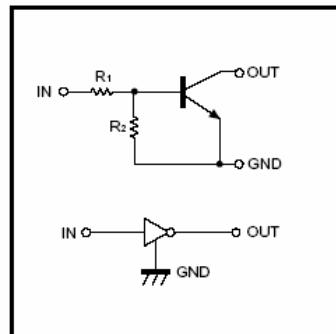


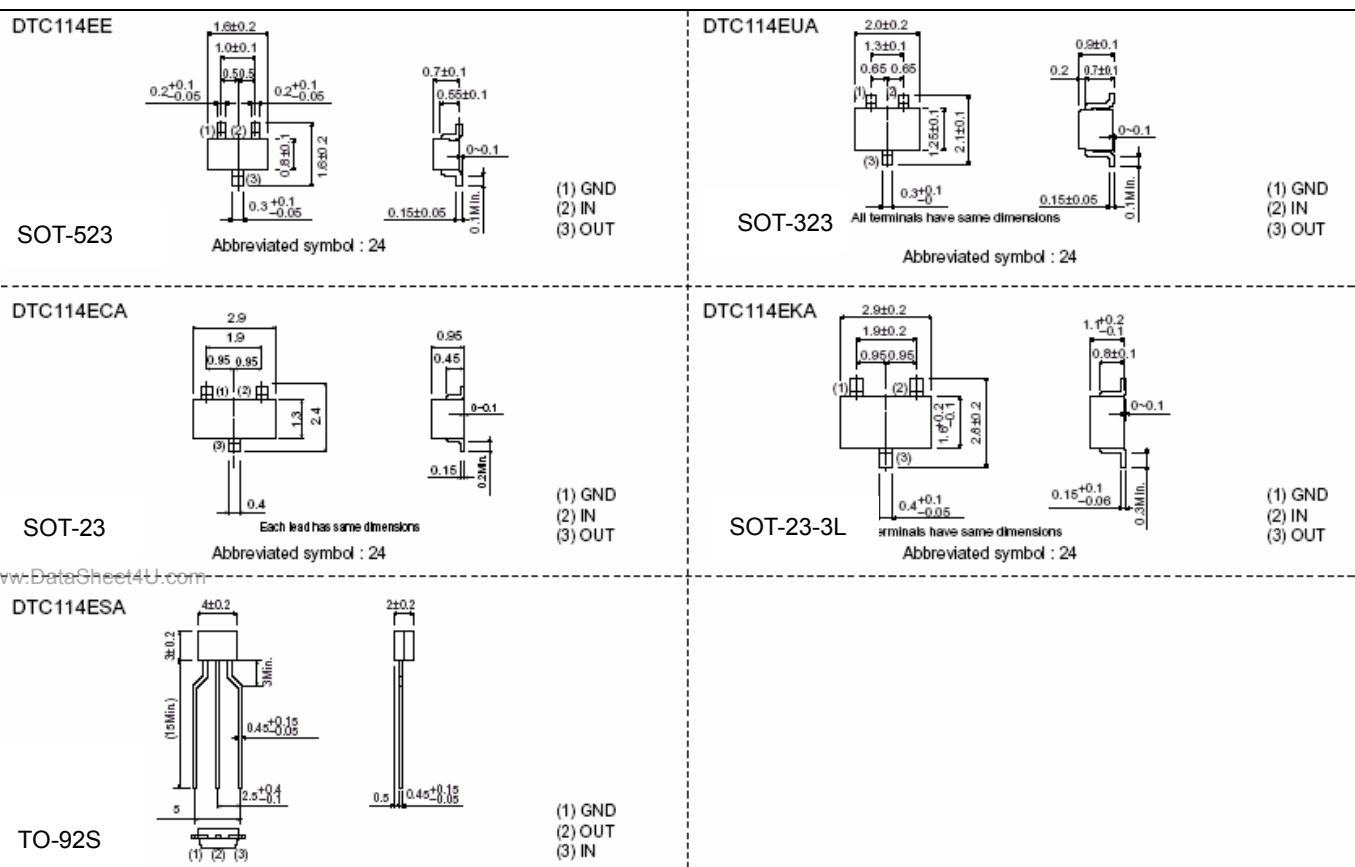
FEATURES

- * Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- * Only the on/off conditions need to be set for operation making device design easy.
- * The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.

● Equivalent circuit



External dimensions (Units:mm)



Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTC114E□)					Unit
		E	UA	CA	KA	SA	
Supply voltage	V _{CC}			50			V
Input voltage	V _{IN}			-10~40			V
Output current	I _O			50			mA
	I _{C(MAX)}			100			
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j			150			°C
Storage temperature	T _{stg}			-55~150			°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			0.5	V	V _{CC} =5V , I _O =100μA
	V _{I(on)}	3				V _O =0.3V , I _O =10 mA
Output voltage	V _{O(on)}			0.3	V	I _O /I _I =10mA/0.5mA
Input current	I _I			0.88	mA	V _I =5V
Output current	I _{O(off)}			0.5	μA	V _{CC} =50V, V _I =0
DC current gain	G _I	30				V _O =5V , I _O =5mA
Input resistance	R _I	7	10	13	KΩ	
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		
Transition frequency	f _T		250		MHz	V _{CE} =10V , I _E =-5mA,f=100MHz

Typical Characteristics

● Electrical characteristic curves

